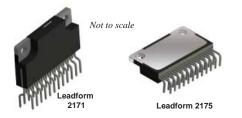


Features and Benefits

- Built-in pre-drive IC
- MOSFET power element
- Alleviate noise generation by adjusting an internal resistor
- CMOS compatible input (5 V)
- High-side gate driver using bootstrap circuit or floating power supply
- Built-in protection circuit for controlling power supply voltage drop (UVLO on VCC)
- Overcurrent protection (OCP), overcurrent limiting (OCL), and thermal shutdown (TSD)
- Output of fault signal during operation of protection circuit
- Output current 2.5 A
- Small SIP (SLA 24-pin)

Packages: Power SIP



Description

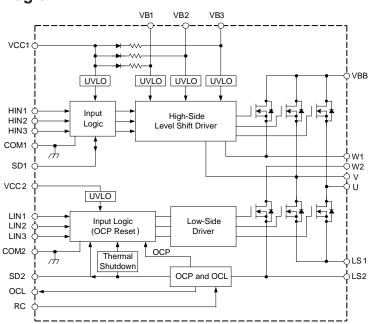
The SLA6868M inverter power module (IPM) device provides a robust, highly-integrated solution for optimally controlling 3-phase motor power inverter systems and variable speed control systems used in energy-conserving designs to drive motors of residential and commercial appliances. These ICs take 230 VAC input voltage, and 2.5 A (continuous) output current. They can withstand voltages of up to 500 V (MOSFET breakdown voltage).

The SLA6800M power package includes an IC with all of the necessary power elements (six MOSFETs), pre-driver ICs (two), and bootstrap diodes (three), needed to configure the main circuit of an inverter. This enables the main circuit of the inverter to be configured with fewer external components than traditional designs.

Applications include residential white goods (home applications) and commercial appliance motor control:

- Air conditioner fan
- Refrigerator compressor
- Dishwasher pump

Functional Block Diagram



A. SD1, SD2 terminals are used for both input and output.

B. SD1, SD2, and OCL terminals are open-collector output. RC terminal is open-drain output. C. Blanking Time (t_{blank}) is used in Overcurrent Limiting (OCL) and Overcurrent Protection (OCP). If the time exceeds the limit, the signal will be output (open-collector output turns on), and protection operation will start up.

Figure 1. Driver block diagram.

High Voltage 3-Phase Motor Driver

Selection Guide

		MOSFET Breakdown	Output Current		
Part Number	Packing	Voltage, V _{DSS} (min) (V)	Continuous, I _O (max) (A)	Pulsed, I _{OP} (max) (A)	
SLA6868M	18 pieces per tube	500	2.5	5	

Absolute Maximum Ratings, valid at $T_A = 25^{\circ}C$

Characteristic	Symbol	Remarks	Rating	Unit
MOSFET Breakdown Voltage	V _{DSS}	$V_{CC} = 15 \text{ V}, I_D = 100 \mu\text{A}, V_{IN} = 0 \text{V}$	500	V
Logic Supply Voltage	V _{cc}	Between VCC and COM	20	V
Bootstrap Voltage	V _{BS}	Between VB and HS (U,V, and W phases)	20	V
Output Current, Continuous	Ιo		2.5	А
Output Current, Pulsed	I _{OP}	$PW \le 100 \ \mu s$, duty cycle = 1%	5	А
Input Voltage	V _{IN}	HINx and LINx pins	-0.5 to 7	V
Pull-up Voltage for Shutdown Pins	V _{SDX}	SDx pins	7	V
Pull-up Voltage for Overcurrent Limiting Pin	V _{OCL}		7	V
Allowable Power Dissipation	PD	$T_{C} = 25^{\circ}C$	32.9	W
Thermal Resistance (Junction to Case)	R _{θJC}	All elements operating	3.8	°C/W
Case Operating Temperature	T _{COP}		-20 to 100	°C
Junction Temperature (MOSFET)	TJ		150	°C
Storage Temperature	T _{stg}		-40 to 150	°C

Recommended Operating Conditions

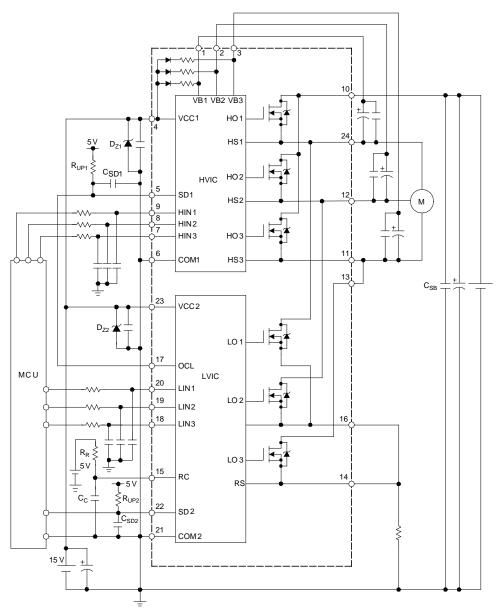
Characteristic	Symbol	Remarks	Min.	Тур.	Max.	Units
Main Supply Voltage	V _{BB}	Between VBB and LS	-	-	400	V
V _{BB} Snubber Capacitor	C _{SB}		0.01	-	0.1	μF
Logic Supply Voltage	V _{CC}	Between VCC and COM	13.5	15	16.5	V
Zener Voltage for VCCx Pins	Vz	Between VCC and COM	18	-	20	V
Pull-up Voltage	V _{SDx} , V _{OCL}		4.5	5	5.5	V
Pull-up Resistor SDx Pins	R _{UPX}		3.3	-	10	kΩ
Pull-up Resistor OCL Pin	R _{OCL(up)}		1	-	10	kΩ
Pull-up Resistor RC Pin	R _R		33	_	390	kΩ
Capacitor SDX and OCL Pins	C _{SDX} , C _{OCL}		1	_	10	nF
Capacitor RC Pin	Cc		1	-	4.7	nF
Dead Time	t _{dead}	$T_J = -20^{\circ}C$ to $150^{\circ}C$	1.5	-	-	μs
Minimum Innut Dules Minit	I _{INMIN(on)}	$T_J = -20^{\circ}C$ to $150^{\circ}C$	0.5	-	-	μs
Minimum Input Pulse Width	I _{INMIN(off)}	$T_J = -20^{\circ}C$ to $150^{\circ}C$	0.5	-	-	μs
Switching Frequency	f _{PWM}		-	_	20	kHz
Junction Temperature	TJ		-	-	125	°C

All performance characteristics given are typical values for circuit or system baseline design only and are at the nominal operating voltage and an ambient temperature, T_A , of 25°C, unless otherwise stated.





Typical Application Diagram



NOTE:

• The external electrolytic capacitors should be placed as close to the IC as possible, in order to avoid malfunctions from external noise interference. Put a ceramic capacitor in parallel with the electrolytic capacitor if further reduction of noise susceptibility is necessary.





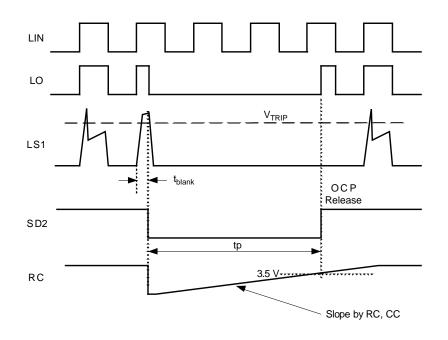
Characteristics	Symbol	Conditions	Min	Тур	Max	Units
Logic Supply Current	I _{CC}	$V_{CC} = 15 \text{ V}, T_{C} = -20^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$	-	4.2	7	mA
Bootstrap Supply Current	I _{BX}	V _{BX} = 15 V, V _{HIN} = 5 V	-	135	380	μA
	VIH	V _{CC} = 15 V	-	2.9	3.4	V
Input Voltage	VIL	V _{CC} = 15 V	1.6	2.1	_	V
Input Voltage Hysteresis	V _{Ihys}	V _{CC} = 15 V	-	0.8	-	V
Input Current	I _{IN}	V _{IN} = 5 V	-	230	500	μA
	V _{UVHL}	High side, between V/Px and U, V/ or W/	9.0	10.0	11.0	V
	V _{UVHH}	High side, between VBx and U, V, or W		10.5	11.5	V
Linden voltoge Leek Out	V _{UVHhys}	High side, hysteresis	-	0.5	-	V
Undervoltage Lock Out	V _{UVLL}	Low side, between VCC2 and COM2	10.0	11.0	12.0	V
	V _{UVLH}		10.5	11.5	12.5	V
	V _{UVLhys}	Low side, hysteresis	-	0.5	_	V
SDx and OCL Output Voltage	V _{SDX(on)} , V _{OCL}	$V_{SDX} = V_{OCL} = 5 \text{ V}, \text{ R}_{UPX} = 3.3 \text{ k}\Omega$	-	-	0.6	V
Overtemperature DetectionThreshold	T _{DH}	V_{CC} = 15 V, high-side and low side	120	135	150	°C
Temperature (Activation and	T _{DL}		100	115	130	°C
Deactivation)	T _{Dhys}		-	20	_	°C
Overcurrent Protection Trip Voltage	V _{TRIP}	V _{CC} = 15 V	0.9	1.0	1.1	V
Overcurrent Protection Hold Time	tp	V_{RC} = 5 V, R_R = 360 kΩ, C_C = 0.0047 μF	-	2.0	-	ms
Blanking Time	t _{blank}	$V_{CC} = 15 V$	1.4	2.0	2.6	μs
Bootstrap Diode Leakage Current	I _{LBD}	V _R = 500 V	-	-	10	μA
Bootstrap Diode Forward Voltage	V _{FBD}	I _F = 0.15 A	-	1.1	1.3	V
Bootstrap Diode Recovery Time	t _{rrb}	I _F / I _{RP} = 100 mA / 100 mA	-	70	-	ns
Bootstrap Diode Series Resistor	R _{BD}		168	210	252	Ω
MOSFET Breakdown Voltage	V _{DSS}	$V_{CC} = 15 \text{ V}, \text{ I}_{D} = 100 \mu\text{A}, V_{\text{IN}} = 0 V$	500	-	_	V
MOSFET Leakage Current	I _{DSS}	$V_{CC} = 15 \text{ V}, V_{DS} = 500 \text{ V}, V_{IN} = 0 \text{ V}$	-	-	100	μA
MOSFET On State Resistance	R _{DS(on)}	$V_{CC} = 15 \text{ V}, \text{ I}_{D} = 1.5 \text{ A}, \text{ V}_{IN} = 5 \text{ V}$	-	2.0	2.4	Ω
MOSFET Diode Forward Voltage	V _{SDF}	$V_{CC} = 15 \text{ V}, \text{ I}_{SD} = 1.5 \text{ A}, \text{ V}_{IN} = 0 \text{ V}$	-	1.1	1.5	V
	t _{dH(on)}	$V_{BB} = 300 \text{ V}, \text{ V}_{CC} = 15 \text{ V}, \text{ I}_{D} = 2.5 \text{ A}, 0 \text{ V} \le \text{ V}_{IN} \le 5 \text{ V}$	-	790	-	ns
	t _{rH}		-	60	-	ns
Switching Time, High Side	t _{rrH}		-	115	-	ns
	t _{dH(off)}		-	725	-	ns
	t _{fH}		_	20	-	ns
	t _{dL(on)}		_	680	-	ns
	t _{rL}		_	70	_	ns
Switching Time, Low Side	t _{rrL}		_	120	_	ns
	t _{dL(off)}	1		605	_	ns
	t _{fL}	1	-	20	_	ns

ELECTRICAL CHARACTERISTICS, valid at $T_A {=} 25^\circ C,$ unless otherwise noted





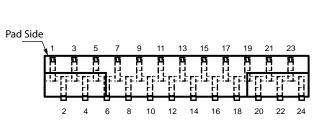
Low-Side Input/Output Timing Diagram



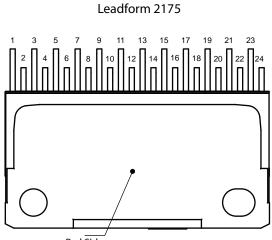




Pin-out Diagram



Leadform 2171



Pad Side

Terminal List Table				
Number	Name	Function		
1	VB1	High side bootstrap terminal (U phase)		
2	VB2	High side bootstrap terminal (V phase)		
3	VB3	High side bootstrap terminal (W phase)		
4	VCC1	High side logic supply voltage		
5	SD1	High side shutdown input and overtemperature fault signal output		
6	COM1	High side logic GND terminal		
7	HIN3	High side input terminal (W phase)		
8	HIN2	High side input terminal (V phase)		
9	HIN1	High side input terminal (U phase)		
10	VBB	Main supply voltage		
11	W1	Output of W phase (connect to W2 externally)		
12	V	Output of V phase		
13	W2	Output of W phase (connect to W1 externally)		
14	LS2	Low side emitter terminal (connect to LS1 externally)		
15	RC	Overcurrent protection hold time adjustment input terminal		
16	LS1	Low side emitter terminal (connect to LS2 externally)		
17	OCL	Output for overcurrent limiting		
18	LIN3	Low side input terminal (W phase)		
19	LIN2	Low side input terminal (V phase)		
20	LIN1	Low side input terminal (U phase)		
21	COM2	Low side GND terminal		
22	SD2	Low side shutdown input and overtemperature and overcurrent fault signals output		
23	VCC2	Low side logic supply voltage		
24	U	Output of U phase		





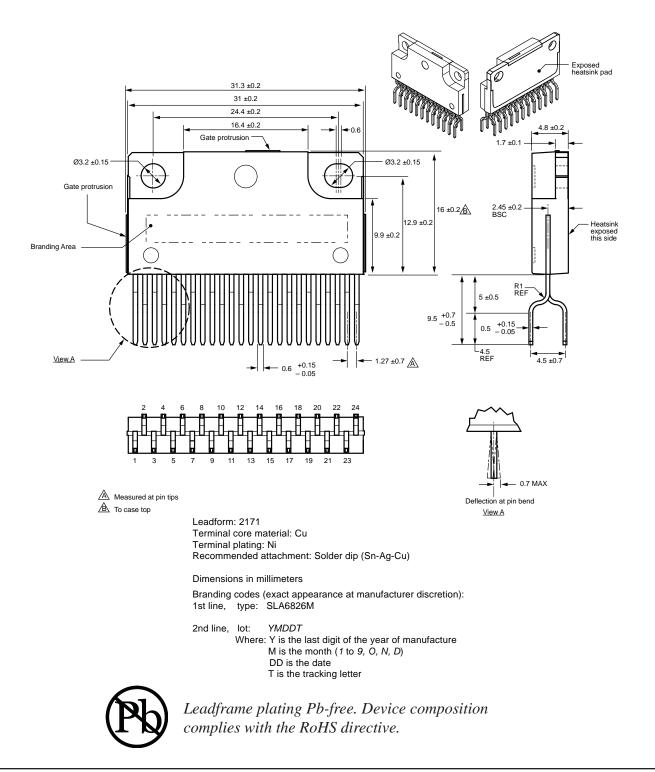


High Voltage 3-Phase Motor Driver

Package Outline Drawing

Leadform 2171

Dual rows, 24 alternating pins; vertical case mounting; pin #1 on tab side



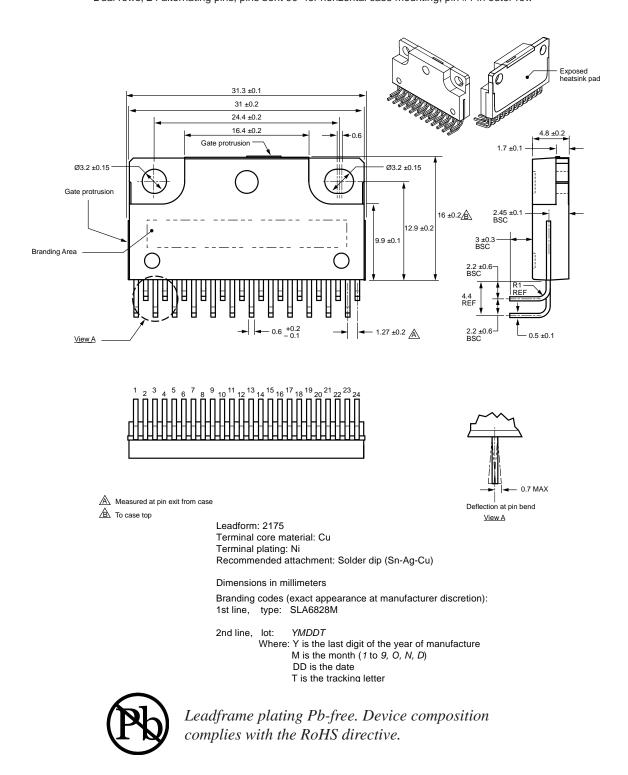




High Voltage 3-Phase Motor Driver

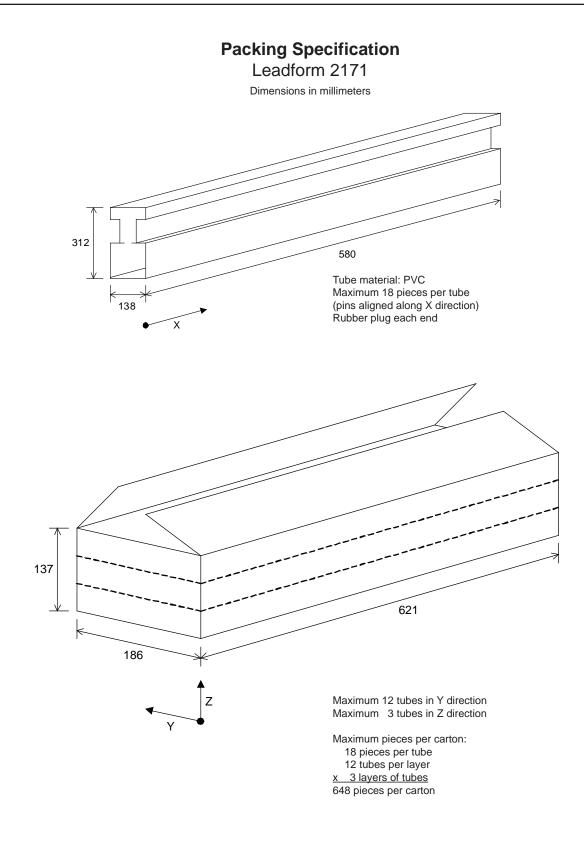
Package Outline Drawing Leadform 2175

Dual rows, 24 alternating pins; pins bent 90° for horizontal case mounting; pin #1 in outer row



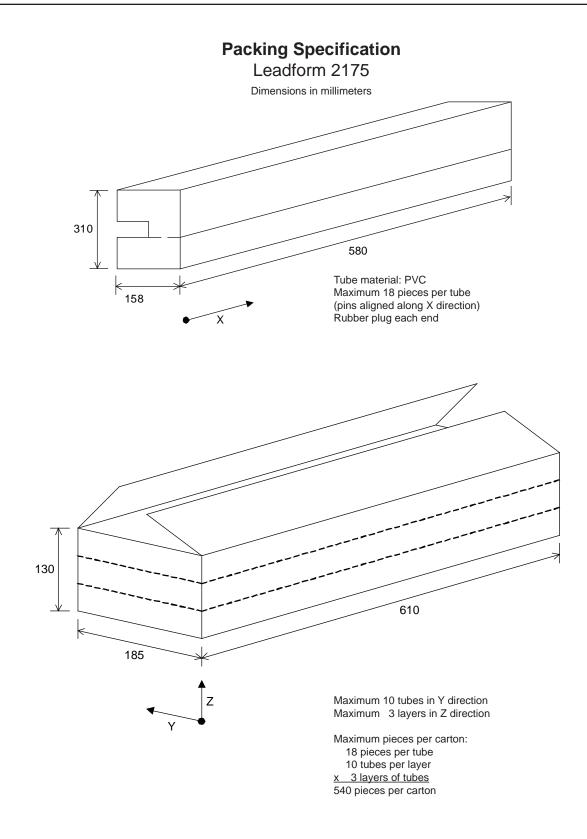
















High Voltage 3-Phase Motor Driver



WARNING — These devices are designed to be operated at lethal voltages and energy levels. Circuit designs that embody these components must conform with applicable safety requirements. Precautions must be taken to prevent accidental contact with power-line potentials. Do not connect grounded test equipment.

The use of an isolation transformer is recommended during circuit development and breadboarding.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40 to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of products that have been stored for a long time.

Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between adjacent products, and shorts to the heatsink.

Remarks About Using Silicone Grease with a Heatsink

- When silicone grease is used in mounting this product on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce stress.
- Volatile-type silicone greases may permeate the product and produce cracks after long periods of time, resulting in reduced heat radiation effect, and possibly shortening the lifetime of the product.
- Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

Туре	Suppliers
G746	Shin-Etsu Chemical Co., Ltd.
YG6260	Momentive Performance Materials, Inc.
SC102	Dow Corning Toray Silicone Co., Ltd.

Heatsink Mounting Method

Torque When Tightening Mounting Screws. The recommended tightening torque for this product package type is: 58.8 to 78.4 N•cm (6.0 to 8.0 kgf•cm).

Soldering

• When soldering the products, please be sure to minimize the working time, within the following limits:

260±5°C 10 s

380±5°C 5 s

• Soldering iron should be at a distance of at least 1.5 mm from the body of the products

Electrostatic Discharge

- When handling the products, operator must be grounded. Grounded wrist straps worn should have at least 1 MΩ of resistance to ground to prevent shock hazard.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in other to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in our shipping containers or conductive containers, or be wrapped in aluminum foil.





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